INTRODUCTION

Power is one of the major considerations in portable, battery-powered applications because of battery life and heat. Since the Audio Power Amplifier (APA) is an important power dissipating building block used in end applications such as cellular telephones, notebook computers, Personal Data Assistants (PDAs), Compact Disc (CD) and Digital Video Disc (DVD) Players, it is worth gaining a clearer understanding of its limitations and ability to deliver power to a load. Once these limitations and abilities are clearly understood, one will be better equipped in determining important parameters such as output power and the resulting Output Sound Pressure Level (SPL) produced by a speaker, input power and the resulting power supply requirements, and package power dissipation and the resulting die junction temperature.

This application note quantifies each of these important parameters and provides supporting empirical data acquired using the TC4864 in the Bridge Tied Load (BTL) topology and the Single-Ended Capacitively Coupled Load (SECL) topology. The BTL topology, as will be shown, is the preferred topology because it can deliver more output power to the load before clipping occurs. This is especially useful in low voltage portable systems where the necessary peak-to-peak voltage swing across the load is greater than the available system power supply voltage. The SECL APA topology is necessary for applications, such as headsets, that contain a speaker (or speakers) and microphone that share the same ground return.

TC4864 AUDIO POWER AMPLIFIER OVERVIEW

The TC4864 is a Class AB Bridged APA capable of delivering a continuous average output power, \( P_{\text{out}} \), of 300 mW (\( V_{\text{DD}} \) = 5V, \( T_A \) = +25°C, \( f = 1 \) kHz) into an 8 \( \Omega \) BTL with a maximum Total Harmonic Distortion Plus Noise (THD+N) of 1%. The maximum \( P_{\text{out}} \) is only slightly greater and is approximately 307 mW and is a consequence of the package power dissipation, \( P_D \), of 595 mW that results in a maximum die junction temperature, \( T_{\text{JMAX}} \), of 150°C assuming a typical junction-to-ambient thermal resistance, \( \theta_{JA} \), for a board mounted MSOP-8 package of approximately 210°C/W. The relationship between output power and package power dissipation will be presented and discussed in detail later in this application note.

The TC4864 has a shutdown pin that can be used to put the part in an extremely "low power" shutdown mode where the quiescent power supply current, \( I_{\text{QDD}} \), drops from a typical value of 4.1 mA to a typical value of 0.1 \( \mu \)A (\( V_{\text{DD}} = 5V \), \( T_A = +25^\circ C \), \( V_{\text{IN}} = 0V \), no load). Depending on the system requirements, a microcontroller can put the part in shutdown mode during periods of "audio inactivity", thereby conserving battery power and reducing heat dissipation. This quiescent power supply current must and will be considered later on in this application note when input power, power dissipation, efficiency and die junction temperature calculations are discussed.

SPEAKER IMPEDANCE

Before moving on to a discussion of the output power, it is beneficial to gain a fundamental understanding of the load impedance presented by a typical speaker since it is this impedance that is ultimately used in the calculation to determine the output power.

There are many types of speaker technologies available with moving coil: (a.k.a. dynamic), electromechanical, and piezoelectric (pressure electricity) being the three most popular. Of these three, the moving coil speaker is probably the most widely used and will, therefore, be discussed in some detail.

An equivalent circuit model can be used to represent the load impedance presented by a typical speaker. In general, this equivalent circuit model contains multiple inductors, resistors and capacitors. Most speaker manufacturers do not specify what the equivalent circuit model should be in order to properly model the speaker's actual impedance vs. frequency. Some of these impedance vs. frequency curves are fairly complicated looking because they can have multiple mechanical and electrical resonant frequencies (especially the piezoelectric speakers).

Piezoelectric speakers basically look like a big capacitor ranging from a few nF up to a hundred nF or so. Basically, a dynamic voltage is applied across a crystal or ceramic material that results in a mechanical strain...
or deflection. One of the benefits of the Piezoelectric speaker is that it does not create a magnetic field, which might be unacceptable in some applications.

Electromechanical speakers look like a complex impedance whose magnitude ranges from a few ohms up to several hundred ohms or so. The electromechanical speaker is composed of a stationary ferrite or ceramic magnet, a stationary coil, and a cone made up of some type of magnetic material. A dynamic voltage is applied across the stationary coil creating a dynamic magnetic field that basically modulates the static magnetic field created by the stationary magnet. The resulting magnetic field then mechanically deflects the magnetic cone material.

The moving coil speaker also looks like a complex impedance whose magnitude ranges from a few ohms up to a hundred ohms or so. The moving coil speaker is composed of a stationary ferrite or ceramic magnet, a moving coil, and a cone that can be made of a plethora of materials. A dynamic voltage is applied across the moving coil via a pair of small, flexible conductors creating a dynamic magnetic field that interacts with the static magnetic field created by the stationary magnet. This magnetic field interaction deflects the moving coil in addition to the cone since the two are mechanically connected together.

The impedance of a moving coil speaker is made up of four parts:
1. The Moving Coil Resistance, $R_{COIL}$.
2. The Moving Coil Inductive Reactance, $X_{COIL}$.
3. The Motional Resistance, $R_{MOT}$.
4. The Motional Reactance, $X_{MOT}$.

The sum of $R_{COIL}$ and $X_{COIL}$ is referred to as the Moving Coil Impedance, $Z_{COIL}$, and the sum of $R_{MOT}$ and $X_{MOT}$ is referred to as the Motional Impedance, $Z_{MOT}$. The sum of $Z_{COIL}$ and $Z_{MOT}$ is the Moving Coil Speaker Equivalent Impedance, $Z_E$.

The Moving Coil Speaker Equivalent Circuit Model is shown in Figure 1.

![Moving Coil Speaker Equivalent Circuit Model](image)

**FIGURE 1:** Moving Coil Speaker Equivalent Circuit Model.

The equations describing this Equivalent Circuit Model are given by:

- Moving coil speaker equivalent impedance:
  \[ Z_E = \frac{V}{I} = Z_{COIL} + Z_{MOT} \]  \[ 1 \]

- Moving coil impedance:
  \[ Z_{COIL} = R_{COIL} + jX_{COIL} \]  \[ 2 \]

- Motional impedance:
  \[ Z_{MOT} = R_{MOT} + jX_{MOT} \]  \[ 3 \]

- Motional resistance:
  \[ R_{MOT} = \frac{1}{\omega C} \left( \frac{1}{RL} \right)^2 \]  \[ 4 \]

- Motional reactance:
  \[ X_{MOT} = \frac{\omega C}{\omega - \frac{1}{RL}} \]  \[ 5 \]

A detailed discussion of each of the components in the equivalent circuit model and the terms in these equations is beyond the scope of this application note; however, the following qualitative statements are worth mentioning:

- $R_{COIL}$ is the resistance and $L_{COIL}$ is the inductance of the very long, thin wire making up the moving coil.
- $R$, $C$ and $L$ making up $Z_{MOT} = R_{MOT} + jX_{MOT}$ are extremely complicated and depend on many factors such as frequency, mass and stiffness of the moving coil and cone, radius of the cone, the static magnetic field produced by the stationary magnet, the length of wire making up the voice coil, etc.

A typical plot of the magnitude of the moving coil speaker equivalent impedance, $|Z_E|$, vs. frequency, $f$, for the CUI Stack, P/N GF0501M, is shown in Figure 2. Notice from this plot that there is a sudden rise in the impedance at a frequency of about 540 Hz. This sudden rise is due to the speaker's mechanical resonance, and $f_0$ denotes the mechanical resonance frequency. As the frequency increases beyond $f_0$, the rise in impedance is due to the inductance of the moving coil. As a rule of thumb, the rated impedance of a moving coil speaker is near the frequency where electrical resonance occurs. Electrical resonance occurs at a frequency beyond $f_0$ where the impedance is at a minimum. This electrical resonance frequency is denoted by $f_R$ and, from the plot in Figure 2, occurs at a frequency of about 1 kHz. The speaker's impedance
for a narrow bandwidth around f_R is fairly constant, and because of this constancy, most manufacturers of moving coil speakers do not specify the exact frequency (sometimes they do) at which the speaker has its rated impedance. In general, a speaker’s rated impedance is measured at a frequency somewhat above f_R and is normally larger than the moving coil resistance, R_COIL. Most people are familiar with these values because they are fairly standard - 4 Ω, 8 Ω, 16 Ω, 32 Ω, etc., R_COIL is slightly less than these values and is typically around 5 Ω or so for a speaker with a rated impedance of 8 Ω.

\[ V_D = \left| V - V_D \right| \quad [6] \]

\[ V_D = \left| V - V_C \right| \quad [7] \]

Where:
- \( V \) is the Positive Supply Voltage Rail (V_DD for the TC4864)
- \( V \) is the Negative Supply Voltage Rail (0V for the TC4864)
- \( V_D \) is the Positive Output Clipping Voltage (<V_DD for the TC4864)
- \( V_C \) is the Negative Output Clipping Voltage (>0V for the TC4864)

Of course, a perfect APA has dropout voltages of 0V. Dropout voltages greater than 0V are the result of voltage drops across the output stage transistors. For the TC4864, \( V_D \) and \( V_C \) are approximately equal and increase as the supply voltage increases. See the TC4864 data sheet for typical plots of the “Dropout Voltage vs. Supply Voltage”. The data sheet plots labeled “Top Side” and “Bottom Side” are the same as \( V_D \) and \( V_C \) respectively. The data for these plots was gathered for a differential voltage gain, A_GAIN of 2 with an 8 Ω BTL. The input signal level was increased until the \( V_{O1} \) output voltage just begins to start clipping and then the dropout voltages were calculated using equations 6 and 7. For a supply voltage of 5V, \( V_D \) is typically around 1V, and \( V_C \) is typically around 0.9V. Since \( V_D \) is greater than \( V_C \), the TC4864, “Top Side” clipping will occur first and then the input signal level will need to be increased slightly to get “Bottom Side” clipping to occur.

A couple of typical \( V_{O1} \) time domain output voltage waveforms are shown in Figures 3 and 4 for clipping levels that result in THD+Ns of 1% and 10%, respectively. \( V_{O1} \) as viewed by a spectrum analyzer in the frequency domain for each of these output voltage waveforms can be seen in Figures 5 and 6, respectively.

**FIGURE 2:** \( |Z_{e}| \) vs. f for the CUI Stack, P/N GF0501M moving coil speaker.

What does one do with all of this information? It is important to understand that it is the moving coil speaker’s equivalent impedance, \( Z_{e} \), which will be used as the load, \( R_L \), to calculate the TC4864’s output power later on in this application note. Although not shown here, \( Z_{e} \) is mostly resistive (real) for the majority of frequencies less than f_R for moving coil speakers. It is this reason that most manufacturers of APAs perform testing and characterization using simple resistive loads. The simple resistive load is fairly standard among the audio community when specifying and characterizing an APA.

**DROPOUT VOLTAGE**

An important consideration for an APA is its ability to apply an undistorted voltage across a load. One of the parameters that limits this ability is the APA’s ability to drive the output voltage as close as possible to either power supply rail without clipping, which can result in significant distortion.

The dropout voltage is a measure of an APA’s “Headroom” and is typically defined as the magnitude of the difference between the positive or negative supply voltage rail and output voltage when clipping occurs such that the Total Harmonic Distortion Plus Noise (THD+N) of the voltage across the load is less than or equal to 1%. In equation form, these definitions are:
FIGURE 3: \( V_{O1} \) vs. t. for the TC4864
\( (V_{DD} = 5V, A_{VD} = 2, 8 \Omega \text{ BTL}, f = 1 \text{ kHz}, \text{THD+N} = 1\%) \).

FIGURE 4: \( V_{O1} \) vs. t. for the TC4864
\( (V_{DD} = 5V, A_{VD} = 2, 8 \Omega \text{ BTL}, f = 1 \text{ kHz}, \text{THD+N} = 1\%) \).

FIGURE 5: \( V_{O1} \) vs. f. for the Time Domain waveform in Figure 3 (THD+N = 1\%).

FIGURE 6: \( V_{O1} \) vs. f. for the Time Domain waveform in Figure 3 (THD+N = 10\%).

The definitions for Total Harmonic Distortion (THD) and Total Harmonic Distortion Plus Noise, THD+N, are given by:

\[
\% \text{ THD} = \frac{\sqrt{H_2^2 + H_3^2 + \ldots + H_N^2}}{\sqrt{H_1^2 + H_2^2 + H_3^2 + \ldots + H_N^2}} \times 100
\]  

\[
\% (\text{THD+N}) = \frac{\sqrt{H_2^2 + H_3^2 + \ldots + H_N^2 + e_n^2}}{\sqrt{H_1^2 + H_2^2 + H_3^2 + \ldots + H_N^2 + e_n^2}} \times 100
\]

Where:

\( H_2^2 \) = Mean Squared Voltage of Fundamental Frequency  
\( H_N^2 \) = Mean Squared Voltage of \( N^{th} \) Harmonic Frequency  
\( e_n^2 \) = Mean Squared Noise Voltage

The \%THD can be estimated from the frequency domain plots in Figures 5 and 6 and can be calculated using the amplitudes for markers 1-7 (2\(^{nd}\) - 8\(^{th}\) order harmonics respectively). The results yield a \%THD of 0.998\% for Figure 5 and 9.764\% for Figure 6. The slight deviations from the expected THD+N values of 1\% and 10\%, respectively are due to the fact that the remaining higher order harmonics and noise were not included in the calculations. Most audio analyzers, such as the Agilent 8903B, measure THD+N and have selectable bandwidth limiting, low-pass filters. For example, the 8903B has a 30 kHz or 80 kHz low-pass filter that can be selected to allow the user to reduce the number of harmonics used in the measurement.

The human ear is capable of detecting a THD as low as 0.6\% due to only the 2\(^{nd}\) order harmonic and 0.25\% due to only the 3\(^{rd}\) order harmonic. As odd as it might seem, distorted signals containing only a small amount of 2\(^{nd}\) order harmonic distortion are actually perceived as being more "musical" by the human ear. It is the
higher order harmonics such as the 7th, 9th, 11th and 13th that are perceived as more objectionable by the human ear. These higher order harmonics are referred to as the "Dissonant Harmonics", and it is these harmonics that contribute to the deterioration of sound quality resulting from output signal clipping.

It is important that the designer clearly understand dropout voltages and the range of the input signal level, so the TC4864's gain can be adjusted accordingly to avoid excessive clipping of the output signal. Also, dropout voltages will increase with temperature, so appropriate heatsinking measures should be taken to reduce the TC4864's die junction temperature, $T_J$. This will be discussed later in this application note.

OUTPUT POWER

Calculating the output power, $P_{OUT}$, for the BTL and SECCCL topologies is fairly straightforward. Typical BTL and SECCCL topologies using the TC4864 can be seen in Figure 9, and the output voltage waveforms for these topologies can be seen in Figures 7 and 8, respectively. For both topologies, the input signal, $V_{in}$, was set to $0.5V_p$ ($1V_p$), and the external gain setting resistors, $R_C$ and $R_V$, were made equal to 20 kΩ. For the BTL topology, this yields a differential voltage gain of $A_{VD} = -2(R_C/R_V) = -2$, and for the SECCCL topology, this yields a voltage gain of $A_V = -R_V/R_V = -1$.

**FIGURE 7**: Output voltage waveforms for the typical BTL Topology in Figure 9.

**FIGURE 8**: Output voltage waveforms for the typical SECCCL topology in Figure 9.

**FIGURE 9**: Typical BTL and SECCCL topologies using the TC4864.
The equations for calculating $P_{OUT}$ for both topologies are:

**BTL:**

$$P_{OUT} = \left( \frac{A_{VD} V_{IN}}{R_L} \right)^2 + \frac{V_{OS}^2}{2R_L} = \frac{A_{VD}^2 V_{IN}^2}{2R_L} + \frac{V_{OS}^2}{2R_L} \quad [10]$$

**SECLL:**

$$P_{OUT} = \left( \frac{A_V V_{IN}}{R_L} \right)^2 = \frac{A_V^2 V_{IN}^2}{2R_L} \quad [11]$$

Where:

$V_{IN}$ = Peak Input Voltage

Differential Voltage Gain:

$$A_{VD} = \frac{V_{O1} - V_{O2}}{V_{IN}} \quad A_{DD} = \frac{V_{OD}}{V_{IN}} = -\frac{R_F}{R_I}$$

Voltage Gain:

$$A_V = \frac{V_O}{V_{IN}} = \frac{R_F}{R_I}$$

The additional term in the $P_{OUT}$ equation for the BTL topology is due to the differential output offset voltage, $V_{OS}$. $V_{OS}$ is defined as the difference between the $V_{O1}$ and $V_{O2}$ DC output voltages when the input voltage, $V_{IN} = 0V$. For the TC4864, $V_{OS}$ is typically only 5 mV, so it only contributes slightly to $P_{OUT}$ when a practical load is connected. For an 8 Ω load, this term would typically only be 3.125 μW, which can basically be ignored; however, it will contribute to the quiescent power supply current, $I_{DDQ}$, as will be discussed in more detail in the section on input power. Notice that the $P_{OUT}$ equation for the SECLL topology does not include this $V_{OS}$ term because of the AC coupling (DC blocking) output capacitor, $C_C$.

Some comments regarding the BTL and SECLL topologies are in order. As can be seen from Figure 9, the SECLL topology requires a very large coupling capacitor, $C_C$. This capacitor is needed to remove the TC4864’s DC bias voltage of $V_{OD}/2$ that appears at $V_{O1}$ (see Figure 8). If $C_C$ were not used, then large DC currents would flow through the speaker resulting in a large moving coil and cone displacement. This displacement will have an impact on the speaker’s dynamic range of motion before severe distortion occurs. Also, depending on the speaker’s maximum input power, the large DC current could permanently damage the speaker’s moving coil. Of course, $C_C$ increases cost, takes up PCB real estate, and creates a low frequency breakpoint, $f_b$, given by $1/(2πR_CLC_C)$. Large values of $C_C$ are normally required in order to set $f_b$ at some reasonable value. For example, for an $R_L$ of 8 Ω, a $C_C$ of 1000 μF is required for an $f_b$ of 20 Hz, or for an $f_b$ of 200 Hz, $C_C$ need only be 100 μF. Unfortunately, some applications require the SECLL topology, such as headsets which contain a speaker (or speakers) and microphone that share the same ground return. Careful study of equations 10 and 11 will show that the BTL topology results twice the voltage swing across the load and four times the power delivered to the load before clipping of the output voltage occurs. This is especially useful in low voltage portable systems where the necessary peak-to-peak voltage swing across the load is greater than the available system power supply voltage.

In conclusion of this section, $P_{OUT}$ is important for a couple of reasons. First, the package power dissipation, $P_{D}$, is a function of $P_{OUT}$. Understanding this relationship is important when calculating the die junction temperature, as we shall see later on. Second, $P_{OUT}$ is the input power to the speaker being driven. This input power must be appropriate so as not to damage the speaker, and it is also important because the Output Sound Pressure Level, SPL, produced by the speaker is usually specified at some input power. For example, the CUI Stack P/N GF0501M mentioned earlier, is rated for a maximum input power of 1 W and a nominal input power of 0.5 W. The SPL at a distance 50 cm away from the speaker is specified as 84 dB ± 3 dB at this nominal input power of 0.5 W. Understanding how this SPL relates to $P_{OUT}$ and how $P_{OUT}$ depends on the input signal, $V_{IN}$, is important in determining the gain for the TC4864.

**INPUT POWER**

The input power, $P_{IN}$, is the power delivered to the TC4864 by the $V_{DD}$ system power supply and must first be determined before one can calculate the APA’s efficiency, $η$, which will be discussed shortly. Also, knowing the $P_{IN}$ requirements assists in determining the overall $V_{DD}$ system power supply requirements.

For the typical BTL and SECLL topologies presented earlier in Figure 9, waveforms for the power supply current, $I_{DD}$, in relation to the output voltage waveforms can be seen in Figures 10 and 11.

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**FIGURE 10**: Power supply current waveform for the typical BTL topology in Figure 9.
The equations for calculating the peak power supply current, $I_{\text{DD},p}$, and average power supply current, $I_{\text{DD}}$, for both topologies are:

**BTL:** Peak $V_{\text{DD}}$ power supply current

$$I_{\text{DD},p} = \frac{V_{\text{DD}}}{R_L} = \frac{|I_{\text{DD}}| |V_{\text{IN},p}|}{R_L}$$  \[12\]

Where:

$V_{\text{DD},p}$ = Peak Differential Output Voltage

**BTL:** Average $V_{\text{DD}}$ power supply current

$$\overline{I_{\text{DD}}} = \frac{2I_{\text{DD}}}{\pi}$$  \[13\]

**SECCl:**

$$I_{\text{DD},r} = \frac{V_{O_r}}{R_L} = \frac{|I_{\text{DD}}| |V_{\text{IN},r}|}{R_L}$$  \[14\]

Where:

$V_{O,r}$ = Peak Output Voltage

**SECCl:**

$$\overline{I_{\text{DD}}} = \frac{I_{\text{DD},r}}{\pi}$$  \[15\]

These relationships are useful when determining the $V_{\text{DD}}$ system power supply requirements.

The equations for calculating $P_{\text{IN}}$ for both topologies are:

**BTL:**

$$P_{\text{IN}} = V_{\text{DD}} \overline{I_{\text{DD}}} = V_{\text{DD}} \frac{2|I_{\text{DD}}| |V_{\text{IN},r}|}{\pi R_L} + V_{\text{DD}} I_{\text{DD},DDQ}$$  \[16\]

**SECCl:**

$$P_{\text{IN}} = V_{\text{DD}} I_{\text{DD},DDQ} = V_{\text{DD}} \frac{|I_{\text{DD}}| |V_{\text{IN},r}|}{\pi R_L} + V_{\text{DD}} I_{\text{DD},DDQ}$$  \[17\]

Where:

$I_{\text{DD},DDQ}$ = Quiescent Power Supply Current

The additional term in the $P_{\text{IN}}$ equations is due to the quiescent power supply current, $I_{\text{DD},\text{Q}}$. $I_{\text{DD},\text{Q}}$ is the additional power supply current needed to power circuitry internal to the TC4864 such as the bias current for the output stage transistors, and for the BTL topology, it includes any additional load current resulting from the differential output offset voltage, $V_{\text{OS}}$. Since $V_{\text{OS}}$ is typically 5 mV, the contribution to $I_{\text{DD},\text{Q}}$ for an 8 Ω load is approximately 0.625 mA. This additional load current does not exist for the SECCl topology because of the AC coupling (DC blocking) output capacitor; therefore, $I_{\text{DD},\text{Q}}$ for the BTL topology will always be greater than it is for the SECCl topology. This can be seen by looking at the minimum values for $I_{\text{DD},\text{Q}}$ in Figures 10 and 11.

Studying equations 16 and 17 and ignoring the terms containing $I_{\text{DD},\text{Q}}$ shows that for the same $V_{\text{DD}}$, $V_{\text{IN},r}$, $R_L$, and $R_t$, the BTL topology results in four times the input power. In reality, since $I_{\text{DD},\text{Q}}$ is not equal to zero, this ratio will be less than four. This can be empirically verified from Figures 10 and 11. From Figure 10, $P_{\text{IN}} = (5V)(81.4 mA) = 0.407 W$ for the BTL topology, and from Figure 11, $P_{\text{IN}} = (5V)(23.35 mA) = 0.117 W$ for the SECCl topology; therefore, this ratio is more typically around 0.407 W/0.117 W = 3.5.

A concluding point needs to be made concerning $I_{\text{DD},\text{Q}}$. Since the TC4864 has a shutdown pin, the part can be put in an extremely "low power" shutdown mode where $I_{\text{DD},\text{Q}}$ drops from a typical value of 4.1 mA to a typical value of 0.1 μA ($V_{\text{DD}} = 5V$, $T_A = +25^\circ C$, $V_{\text{IN}} = 0V$, no load). Depending on the system requirements, a microcontroller can put the part in shutdown mode during periods of "audio inactivity", thereby conserving battery power and reducing heat dissipation for power sensitive portable applications.

**PACKAGE POWER DISSIPATION**

The package power dissipation, $P_p$, is the power actually dissipated by the TC4864 and is simply the difference between the input power, $P_{\text{IN}}$, and output power, $P_{\text{OUT}}$. Calculation of this parameter is necessary in determining the die junction temperature, $T_J$, to see if it falls within an acceptable range. This will be discussed in detail later in the section entitled "Die Junction Temperature Calculations".

The equations for $P_p$ are found by subtracting equations 10 from 16 for the BTL topology and equations 11 from 17 for the SECCl topology. The results are:

**BTL:**

$$P_D = \frac{2 \sqrt{2} V_{\text{DD}}}{\pi R_L} \sqrt{P_{\text{OUT}} \frac{V_{\text{OS}}^2}{R_L} - P_{\text{OUT}} + V_{\text{DD}} I_{\text{DD},DDQ}}$$  \[18\]

**SECCl:**

$$P_D = \frac{\sqrt{2} V_{\text{DD}}}{\pi R_L} \sqrt{P_{\text{OUT}} - P_{\text{OUT}} + V_{\text{DD}} I_{\text{DD},DDQ}}$$  \[19\]
Theoretical typical plots of $P_D$ vs. $P_{OUT}$ can be seen in Figures 12 and 13 for the BTL and SECCCL topologies respectively for several common resistive load values ($R_L = 4 \, \Omega$, 8 $\Omega$ and 16 $\Omega$) at a $V_{DD} = +5V$. Also, typical values were used for the differential output offset voltage ($V_{OS} = 5$ mV) and the quiescent power supply current ($I_{DDQ} = 4.1$ mA).

**Figure 12:** Theoretical typical plots of $P_D$ vs. $P_{OUT}$ for the BTL topology.

![Figure 12](image1.png)

Empirical data plots of $P_D$ vs. $P_{OUT}$ for the TC4864 can be seen in Figures 14 and 15 for the BTL and SECCCL topologies respectively for several common resistive load values ($R_L = 4 \, \Omega$, 8 $\Omega$ and 16 $\Omega$) at a $V_{DD} = +5V$. Appropriate heatsinking measures were taken in the acquisition of this empirical data so as not to exceed the TC4864’s maximum die junction temperature, $T_{JMAX}$. More will be discussed about this topic in the section entitled “Die Junction Temperature Calculations”.

**Figure 14:** Empirical plots of $P_D$ vs. $P_{OUT}$ for the TC4864 for the BTL topology.

![Figure 14](image2.png)

**Figure 15:** Empirical plots of $P_D$ vs. $P_{OUT}$ for the TC4864 for the SECCCL topology.

As can be seen from the theoretical and empirical data plots of $P_{OUT}$ vs. $P_D$, there is a value of $P_{OUT}$ for which $P_D$ is a maximum for each $R_L$. The theoretical values can be found by taking the partial derivative of $P_D$ with respect to $P_{OUT}$, setting the partial derivative equal to zero and then solving for the maximum package power dissipation, $P_{DMAX}$. The results of performing this operation for both topologies are:

**BTL:**

\[
P_{DMAX} = \frac{2V_{DD}^2}{\pi^2 R_L} + \frac{V_{OS}^2}{R_L} + V_{DD}I_{DDQ}
\]  

**SECCCL:**

\[
P_{DMAX} = \frac{V_{DD}^2}{2\kappa^2 R_L} + V_{DD}I_{DDQ}
\]  

[20]  

[21]
The $P_{\text{OUT}}$ values corresponding to these $P_{\text{DMAX}}$ values are:

**BTL:**

$$
P_{\text{OUT}} = \frac{2V_{\text{DD}}^2}{\pi R_L} + \frac{V_{\text{OS}@P_{\text{DMAX}}}}{R_L} \tag{22}
$$

**SECC:**

$$
P_{\text{OUT}} = \frac{V_{\text{DD}}^2}{2\pi R_L} @ P_{\text{DMAX}} \tag{23}
$$

As an example, for $V_{\text{DD}} = +5\,\text{V}$ and $R_L = 8\,\Omega$, $P_{\text{DMAX}} = 654\,\text{mW}$ with a resulting $P_{\text{OUT}} = 633\,\text{mW}$ for the BTL topology, and $P_{\text{DMAX}} = 179\,\text{mW}$ with a resulting $P_{\text{OUT}} = 158\,\text{mW}$ for the SECC topology. These values can be approximately verified by studying the theoretical typical plots in Figures 12, 13 and the empirical data plots in Figures 14 and 15. Typically (no heatsinking) a $P_{\text{OUT}}$ of 633 mW for the BTL topology and 158 mW for the SECC topology will be difficult to achieve with the TC4864 due to excessive die junction temperature and clipping of the output voltage. As previously mentioned, appropriate heatsinking measures were taken in the acquisition of the empirical data so as not to exceed the TC4864’s maximum die junction temperature, $T_{\text{JMAX}}$. Heatsinking of the TC4864 will also increase the output voltage swing before clipping occurs.

What does one do with $P_{\text{DMAX}}$? For input signals where the amplitude is uncontrolled or unpredictable, as is the case with most music or voice-band signals, the value obtained for $P_{\text{DMAX}}$ from either equations 20 or 21 is the conservative value to use when calculating the die junction temperature. For input signals where the amplitude is controlled or predictable, as is the case with alert tones, the value obtained for $P_{\text{D}}$ from either equations 18 or 19 is the appropriate value to use when calculating the die junction temperature. This calculation will be discussed in detail in the “Die Junction Temperature Calculations” section.

**EFFICIENCY**

The efficiency, $\eta$, of an APA is defined as the ratio of $P_{\text{OUT}}$ to $P_{\text{IN}}$. This is easily accomplished by taking the ratio of equations 10 and 16 for the BTL topology and equations 11 and 17 for the SECC topology. The results are:

**BTL:**

$$
\eta = \frac{P_{\text{OUT}}}{P_{\text{IN}}} = \frac{|A_{VP}| V_{\text{IN}} \pi}{2V_{\text{DD}}} \tag{24}
$$

**SECC:**

$$
\eta = \frac{|A_{VP}| V_{\text{IN}} \pi}{2V_{\text{DD}}} \tag{25}
$$

As counterintuitive as it might seem, manipulation of equations 16, 17, 24 and 25 will show that for the same input power, the SECC topology is actually twice as efficient as the BTL topology. In other words, more power is being dissipated by the package, and less power is being delivered to the load. For this reason, when using the TC4864 in the BTL topology, it is especially important to be mindful of the die junction temperature as will be discussed in the next section.

**DIE JUNCTION TEMPERATURE CALCULATIONS**

The die junction temperature, $T_{J}$, is an extremely important parameter since operation at elevated temperatures for extended periods of time results in decreased device reliability which can eventually lead to complete device failure.

Also, reduction of $T_{J}$ will increase the TC4864’s output voltage swing before clipping occurs.

The ever so familiar die junction temperature equation is given by:

$$
T_{J} = T_{A} + P_{D} \theta_{JA} \tag{26}
$$

Therefore,

$$
P_{D} = \frac{T_{J} - T_{A}}{\theta_{JA}} \tag{27}
$$

For $T_{J} = T_{\text{JMAX}} = 150^\circ\text{C}$, $T_{A} = 25^\circ\text{C}$ and $\theta_{JA} = 210^\circ\text{C}/\text{W}$, $P_{D} = 595\,\text{mW}$. The resulting $P_{\text{OUT}}$ can be solved for in equation 18 and is fairly complicated, so the details are omitted. The "theoretical" result for the BTL topology under the conditions $V_{\text{DD}} = 5\,\text{V}$ and $R_L = 8\,\Omega$ is:

\[ 8\Omega\text{BTL: } P_{\text{OUT}} = 307\,\text{mW, and 1.077 W} \]

As odd as it might seem, for the BTL topology, there are actually two “theoretical” solutions for $P_{\text{OUT}}$. This can be seen by studying Figure 12 in the "Package Power Dissipation" section. In practice, however, the TC4864 can never reach 1.077 W due to clipping of the output voltage. Therefore, for the BTL topology, $P_{\text{OUT}} = 307\,\text{mW}$ for a $T_{\text{JMAX}} = 150^\circ\text{C}$. The SECC topology was not considered since it is not possible for $P_{\text{D}}$ to equal 595 mW under these conditions ($V_{\text{DD}} = 5\,\text{V}$ and $R_L = 8\,\Omega$) as can be seen by studying Figure 13 in the "Package Power Dissipation" section.

It should be apparent that by decreasing $\theta_{JA}$, $P_{\text{DMAX}}$ and/or $T_{A}$ can be increased. The easiest way to decrease $\theta_{JA}$ is by connecting large traces or power and ground planes to the device’s $V_{\text{DD}}$ and GND pins. A technique often overlooked or not even considered is removal of the solder mask from these traces and planes close to the device which allows them to dissipate power more efficiently which also aids in decreasing $\theta_{JA}$. 

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CONCLUSIONS

The TC4864 APA is a small, cost effective solution for low voltage portable applications where the need for large, clean output drive voltages is needed. A clear understanding of the basic "Powerful" principles set forth in this application note are crucial for a high performance audio design that is both efficient and reliable.
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